IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants: MURATA, et al.

Serial No.:

Not yet assigned

Filed:

January 14, 2004

For:

A SEMICONDUCTOR INTEGRATED CIRCUIT DEVICE AND A

METHOD OF MANUFACTURING THE SAME

INFORMATION DISCLOSURE STATEMENT UNDER 37 CFR 1.97 & 1.98

Mail Stop DD **Commissioner for Patents** P.O. Box 1450 Alexandria, VA 22313-1450

January 14, 2004

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Sir:

In the matter of the above-identified application, applicants are submitting herewith a copy of the documents listed in the attached form equivalent to Form PTO-1449 for the Examiner's consideration.

This information disclosure statement is being submitted with the new application.

Although some of the documents listed on the attached form equivalent to Form PTO-1449 are not in the English language, the requirement of 37 CFR 1.98(a)(3) for a concise explanation of the relevance is satisfied by the attached English language abstracts.

It is respectfully requested that this information disclosure statement be considered by the Examiner.

Please charge any shortage in the fees due in connection with the filing of this paper, including extension of time fees, to the deposit account of Antonelli, Terry, Stout & Kraus Deposit Account No. 01-2135 (Case: 501.43228X00), and please credit any excess fees to such deposit account.

Respectfully submitted,

ANTONELLI, TERRY, STOUT & KRAUS LLP

Registration No. 28,141

Ronald JiShove Rcg, No. 76,577

GEM/alb (703) 312-6600 **Attachments**

Sheet 1 of 1

Form PTO-1449	U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE	ATTY. DKT. NO. 501.43228X00	SERIAL NO.		
INFORMAT	ION DISCLOSURE STATEMENT BY APPLICANT	APPLICANT MURATA, et al.			
(L	ise several sheets if necessary)	FILING DATE January 14, 2004	GROUP		

U.S. PATENT DOCUMENTS

Examiner Initial	Document Number	Date	Name	Class	Subclass	Filing Date
AA	5,198,683	03/30/1993	1	357	67	05/03/1991
AB	5,670,803		BEILSTEIN, Jr. et al.	257	278	02/08/1995
AC	5,994,735		MAEDA, et al.	257	329	11/30/1999
AD	5,627,390	05/06/1997	MAEDA, et al.	257	302	05/06/1997
AE						
AF						
AG						
AH						
AI						
AJ						
AK						
AL						

FOREIGN PATENT DOCUMENTS

Examiner	Document	ocument			Subclass	Abstract	
Initial	Number	Date	Country	Class		Yes	No
AM	11-176936	07/02/1999	JP	H01L	21/768	X	
AN	9-232447	09/05/1997	JP	H01L	21/8244	X	
AC	2001-28443	01/30/2001	JР	H01L	29/786	X	
AF	6-104405	4/15/1994	JP	H01L	27/11	X	
AC	03/019663	03/06/2003	WO	H01L	27/11		
AF	00/70683	11/23/2000	WO	H01L	27/108		
AS							
AT	`						

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

OTHER DOCUMENTS (including Author, Title, Date, Fertilient Pages, Etc.)				
	AU	WATANABE, et al., "A Novel Circuit Technology with Surrounding Gate Transistors (SGT's) for Ultra High Density DRAM's", IEEE Journal of Solid-State Circuits, Vol. 30, No. 9, September 1995		
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